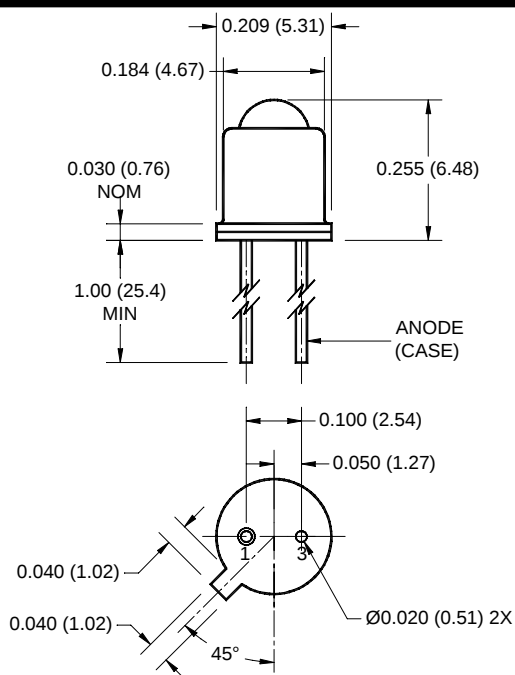


PACKAGE DIMENSIONS



NOTES:

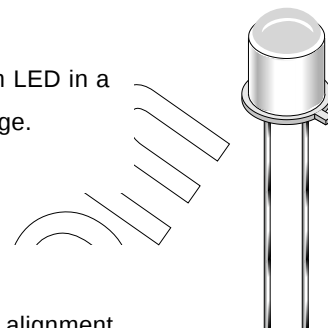
1. Dimensions for all drawings are in inches (mm).
2. Tolerance of $\pm .010$ (.25) on all non-nominal dimensions unless otherwise specified.

DESCRIPTION

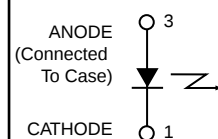
- The F5D series is a 880 nm LED in a narrow angle, TO-46 package.

FEATURES

- Good optical to mechanical alignment
- Mechanically and wavelength matched to the TO-18 series phototransistor
- Hermetically sealed package
- High irradiance level



SCHEMATIC



1. Derate power dissipation linearly 1.70 mW/°C above 25°C ambient.
2. Derate power dissipation linearly 13.0 mW/°C above 25°C case.
3. RMA flux is recommended.
4. Methanol or isopropyl alcohols are recommended as cleaning agents.
5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
6. As long as leads are not under any stress or spring tension
7. Total power output, P_O , is the total power radiated by the device into a solid angle of 2π steradians.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Unit
Operating Temperature	T_{OPR}	-65 to +125	°C
Storage Temperature	T_{STG}	-65 to +150	°C
Soldering Temperature (Iron) ^(3,4,5 and 6)	T_{SOL-I}	240 for 5 sec	°C
Soldering Temperature (Flow) ^(3,4 and 6)	T_{SOL-F}	260 for 10 sec	°C
Continuous Forward Current	I_F	100	mA
Forward Current (pw, 10µs; 100Hz)	I_F	3	A
Forward Current (pw, 1µs; 200Hz)	I_F	10	A
Reverse Voltage	V_R	3	V
Power Dissipation ($T_A = 25^\circ\text{C}$) ⁽¹⁾	P_D	170	mW
Power Dissipation ($T_C = 25^\circ\text{C}$) ⁽²⁾	P_D	1.3	W

ELECTRICAL / OPTICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$) (All measurements made under pulse conditions)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Peak Emission Wavelength	$I_F = 100$ mA	λ_P	—	880	—	nm
Emission Angle at 1/2 Power	$I_F = 100$ mA	θ	—	± 8	—	Deg.
Forward Voltage	$I_F = 100$ mA	V_F	—	—	1.7	V
Reverse Leakage Current	$V_R = 3$ V	I_R	—	—	10	µA
Total Power F5D1 ⁽⁷⁾	$I_F = 100$ mA	P_O	12.0	—	—	mW
Total Power F5D2 ⁽⁷⁾	$I_F = 100$ mA	P_O	9.0	—	—	mW
Total Power F5D3 ⁽⁷⁾	$I_F = 100$ mA	P_O	10.5	—	—	mW
Rise Time 0-90% of output		t_r	—	1.5	—	µs
Fall Time 100-10% of output		t_f	—	1.5	—	µs

Figure 1. Power Output vs. Input Current

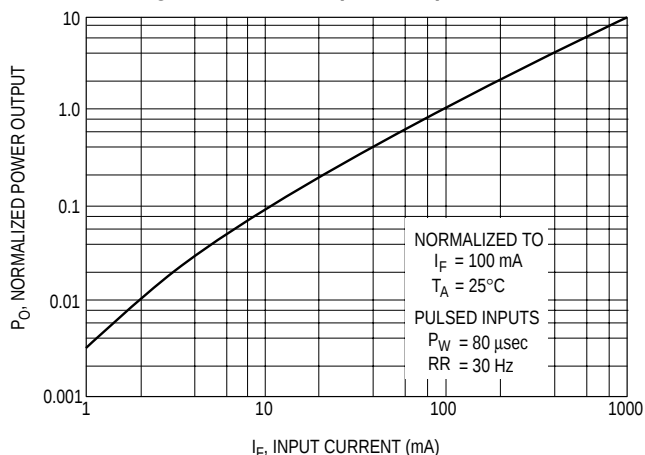


Figure 2. Power Output vs. Temperature

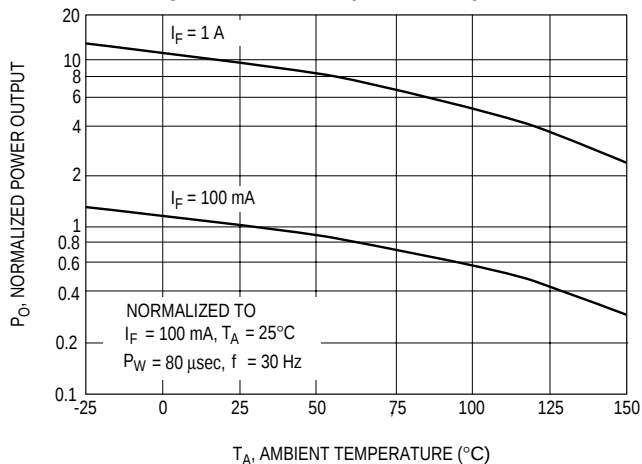


Figure 3. Forward Voltage vs. Temperature

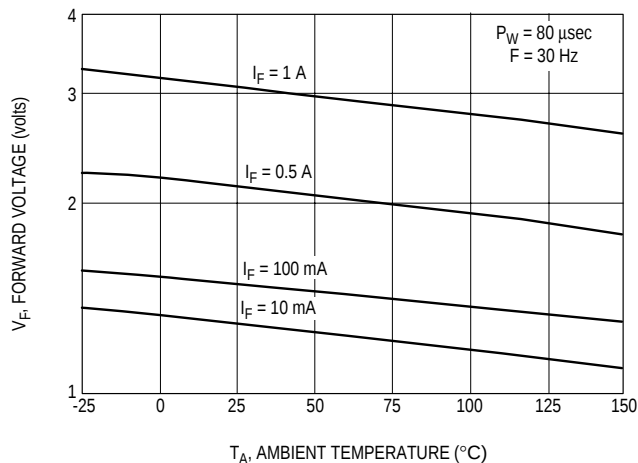


Figure 4. Typical Radiation Pattern

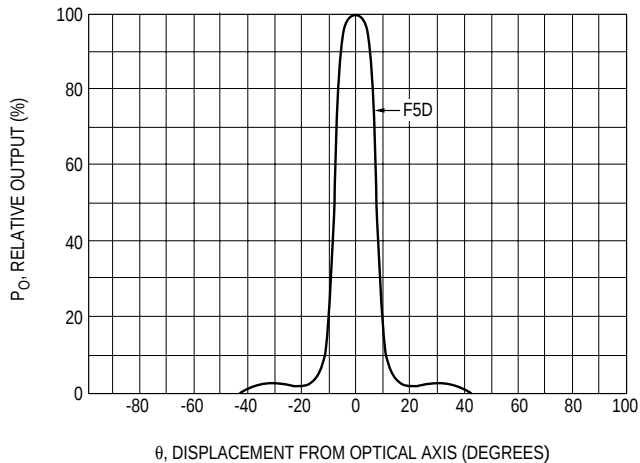


Figure 5. Output vs. Input with L14G Detector

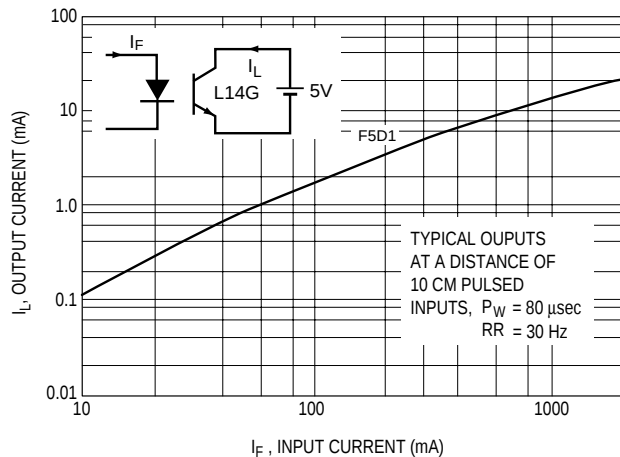
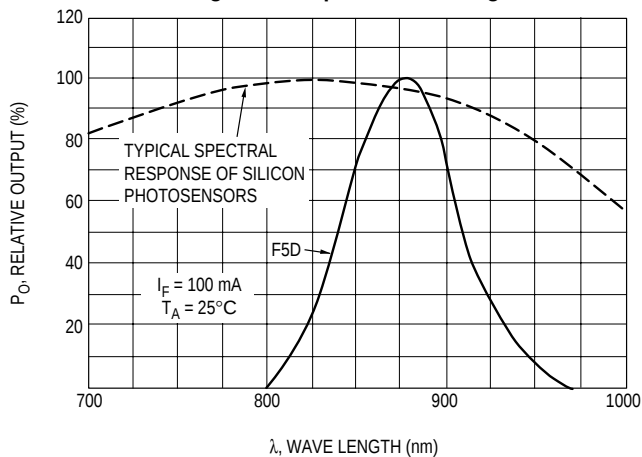


Figure 6. Output vs. Wavelength



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